

Motivation

Molybdenum disulfide, MoS₂, is a layered material from transition metal dichalcogenide (TMD) family. Its range of applications includes tribological coatings, materials for electronics, and catalysis.

TMD thin films are often prepared via deposition processes, that originally yield an amorphous material¹. Tribological applications mostly rely on the ability of MoS₂ to crystallize in the course of exploitation. Other applications require MoS₂ to be crystallized in a certain way: in mild conditions for flexible stretchable photodetectors² or with specific defects for catalysis applications³.

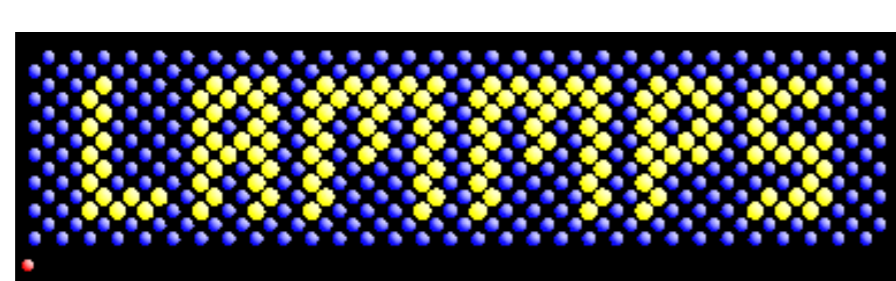
Accurate simulations at a large scale provide insights into collective events and structural changes in the course of transformation and isolate the effects of varying conditions. Those findings can be very useful for guiding experimental search of the treatment conditions.

Several ReaxFF⁴ parameterizations exist for Mo-S system. They were used to study bending of MoS₂ layers⁵, crystallization of a single layer of MoS₂^{6,7}, and formation MoS₂ from MoO₃ and sulfur⁸. None of those, however, yielded a layered MoS₂ in our attempts to crystallize it if it wasn't a single-layer setup. The structures we produced resembled a not-yet-discovered experimentally and non-stable within DFT defective rock-salt type MoS.

In our work on ReaxFF V-O parameterization we found a set that tended to produce layered VO₂ structures resembling MoS₂ layers. Using Chen et al^{5,6} parameters for S atom, we developed this set into a full Mo-S parameterization. Our new Mo-S ReaxFF reproduces the energies of various crystalline Mo_xS_y phases and actually yields layered MoS₂ in crystallization simulations.

Methods

- DFT within VASP, PAW, PBE, E_{cut} = 500 eV
van der Waals interactions – Grimme-D2
U-correction 3.5 eV for Mo atom
- Molecular dynamics – LAMMPS, reax/c package
- ReaxFF parameters:
Chenoweth et al⁹ as a starting point for V-O
Chen et al⁷ – addition for S atom
- ReaxFF development – Monte-Carlo algorithm



Results

ReaxFF validation – crystalline models

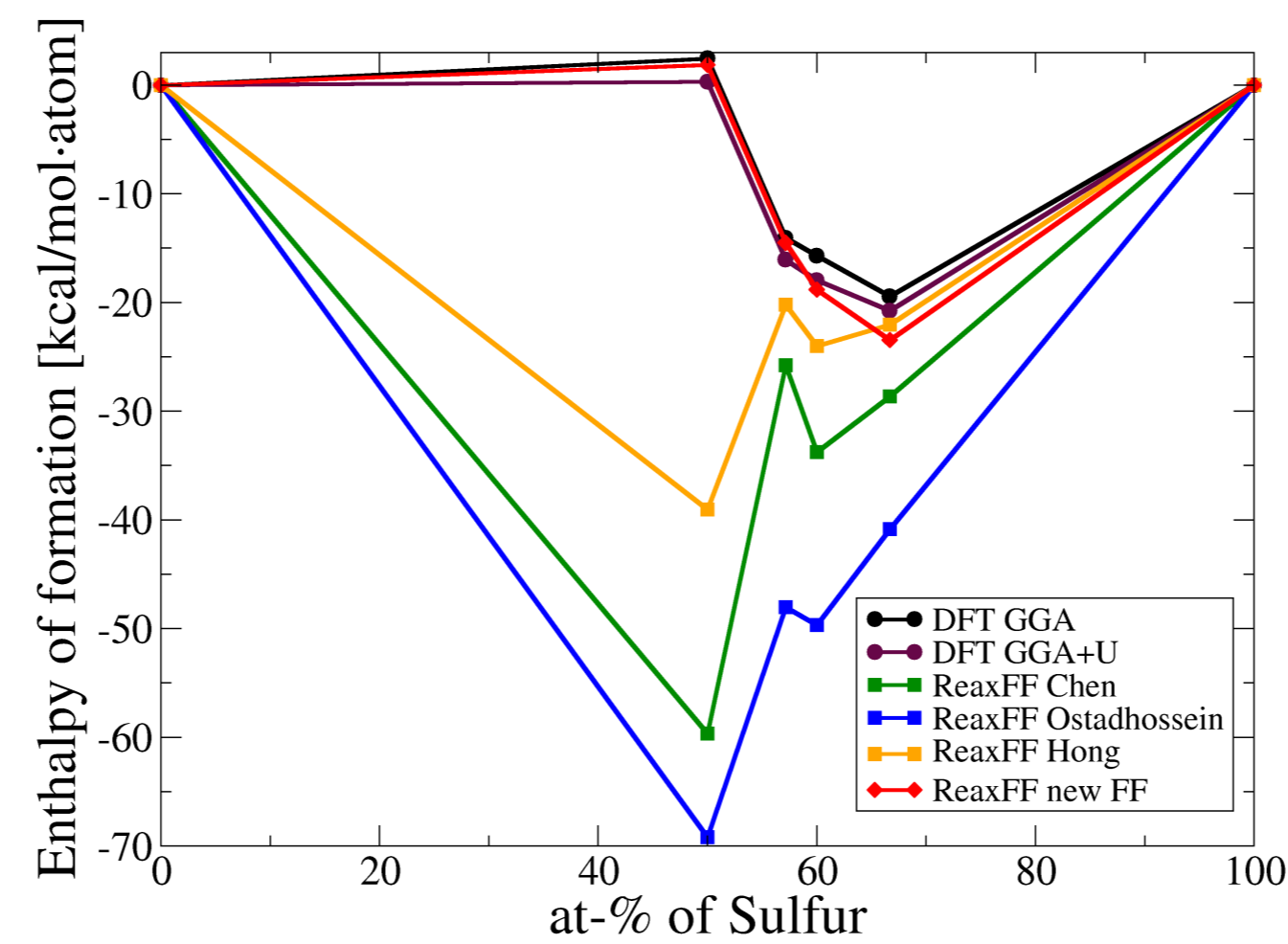


Figure 1. Convex-Hull diagram in Mo-S system computed within DFT and various ReaxFF parameterizations.

Table 1. Structural parameters of DFT- and ReaxFF-optimized MoS₂.

Method	Cell parameters [Å]	
	a	c
Experimental	3.169	12.324
DFT	3.189	12.401
DFT+U	3.199	12.407
ReaxFF new FF	3.209	11.901

- MoS₂ cell parameters – within 5% of experimental and DFT-computed values
- Enthalpies of formation of Mo_xS_y crystals within new FF matches DFT within 4 kcal/mol-atom
- State-of-the-art ReaxFF parameterizations overestimate the stability of hypothetical fcc-MoS.

ReaxFF validation – amorphous models

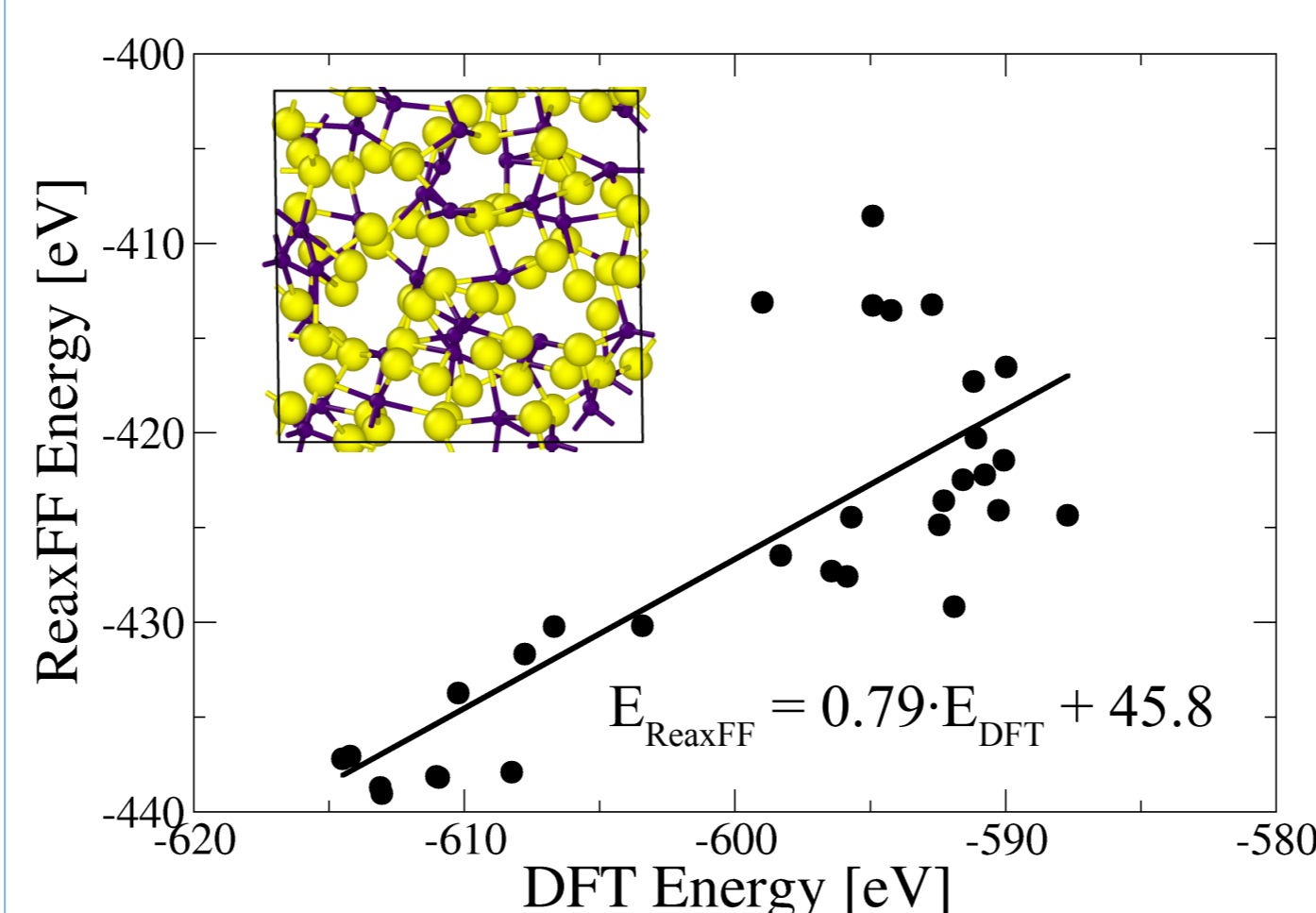


Figure 2. Energies of 105-atom amorphous MoS₂ models, generated via melt-quench within ReaxFF and optimized within DFT. Black line – linear fit, red line – linear fit, slope of 1.

- ReaxFF energies of amorphous MoS₂ correspond well to their DFT energies
- 1 “ReaxFF eV” ≈ 0.8 “DFT eV” in am-MoS₂
- Overall – good performance of the new FF vs. DFT

Results

MoS₂ crystallization – small models

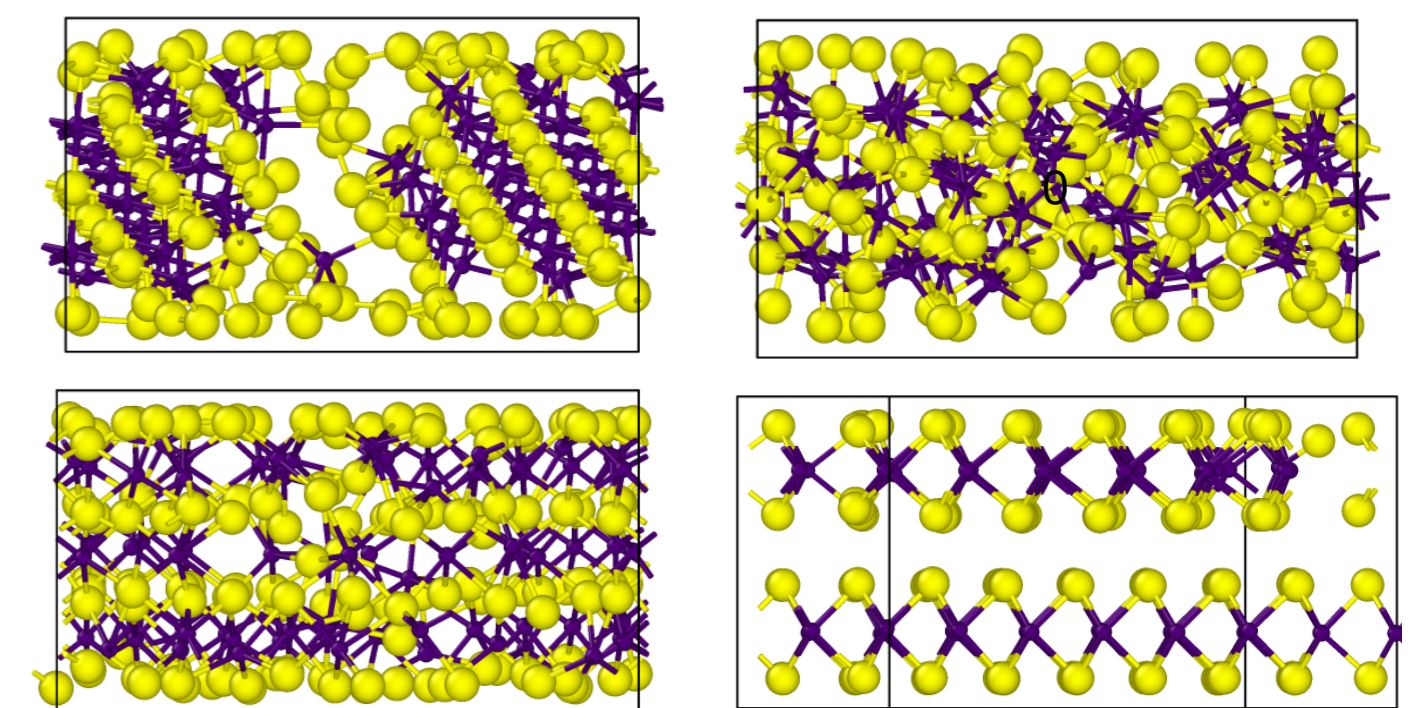


Figure 3. MoS₂ crystallization with different ReaxFF parameter sets: top left – Ostadhossein⁵, top right – Chen⁷, bottom left – Hong⁸, bottom right – our new parameterization. 216 atom model, 2 layers of MoS₂, LJ walls in z-direction; melted at 5000K and then quenched at 10 K/ps.

MoS₂ crystallization – big models

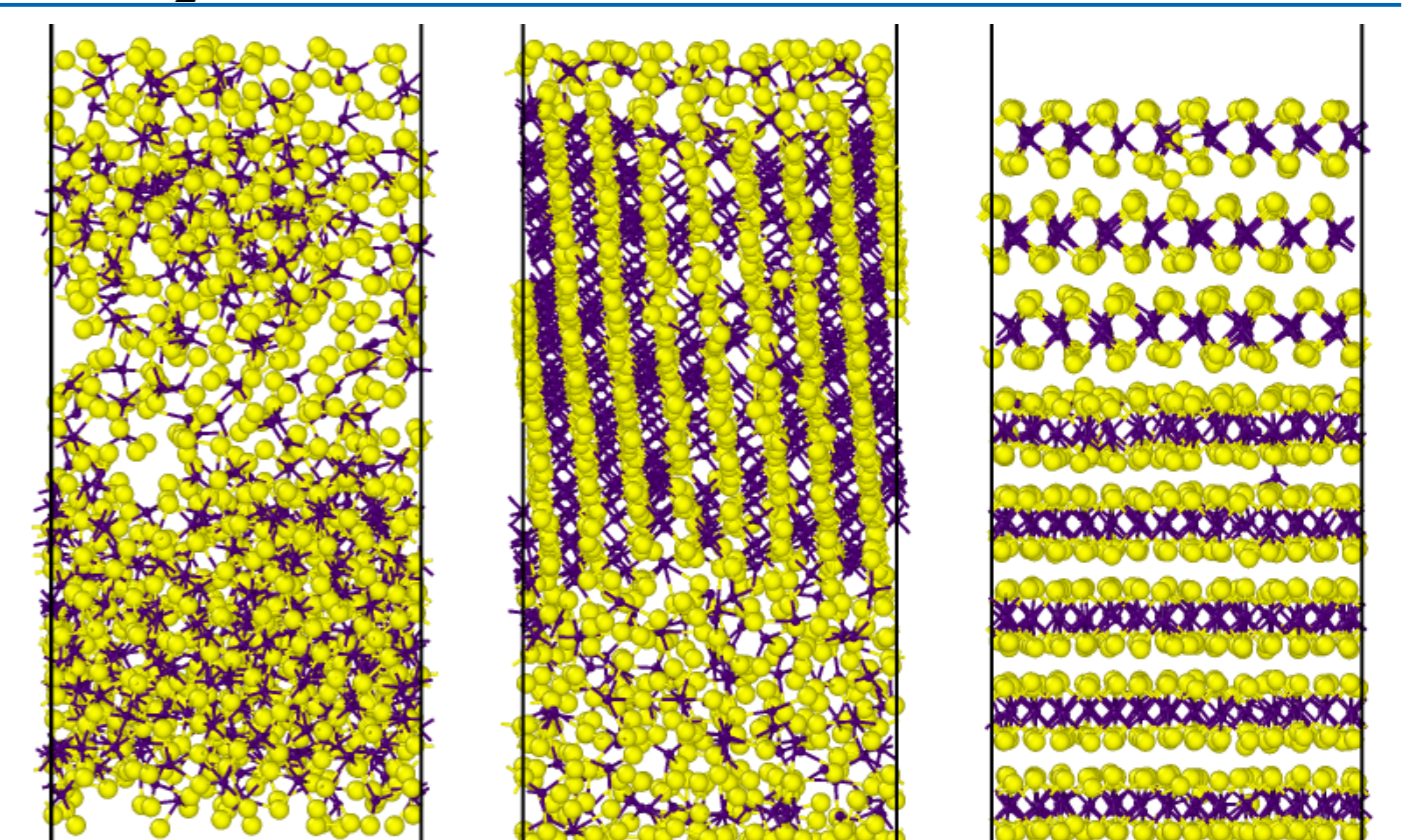


Figure 4. MoS₂ crystallization with different ReaxFF parameter sets: left – Chen⁷, middle – Hong⁸, right – our new parameterization. 1344 atom model, 8 layers of MoS₂, LJ walls in z-direction; melted at 5000K, cooled to 2000K at 10 K/ps and then held at 2000K with top wall wiggling to mimic tribological conditions.

- State-of-the-art force fields: structures resembling rock salt MoS plus sulfur-rich phase
- Our new force field – 2H-MoS₂ layers

Conclusions

- Our new ReaxFF parameter set for Mo-S system:
- Reproduces cell parameters of 2H-MoS₂
 - Reproduces DFT stabilities of crystalline Mo_xS_y
 - Reproduces stabilities for amorphous MoS₂
 - Yields crystallization of layered MoS₂ structures in multiple layer setup, even in relatively big system

References

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Acknowledgments

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